



4-18-05

1 FW 2891
JH

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No. 10/072,415
Filing Date February 5, 2002
Inventor Ji Lee et al.
Assignee Micron Technology, Inc.
Group Art Unit 2891
Examiner V. Yevsikov
Confirmation No. 5182
Customer No. 021567
Attorney's Docket No. MI30-068
Title: Field Effect Transistor Fabrication Methods, Field Emission Device Fabrication Methods, and Field Emission Device Operational Methods

RESPONSE TO DECEMBER 15, 2004 OFFICE ACTION

To: Mail Stop Fee Amendment
Assistant Commissioner for Patents **EV549572104**
P.O. Box 1450
Alexandria VA 22313-1450

From: James D. Shaurette (Tel. 509-624-4276; Fax 509-838-3424)
Wells, St. John, P.S.
601 W. First Avenue, Suite 1300
Spokane, WA 99201-3828

Sir:

Responsive to the Office Action dated December 15, 2004, Applicants amend and
remark as follows:

AMENDMENTS

04/19/2005 WABDEL1 00000004 10072415

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